BOOM	D 2 . C	1 0	10
NO	Description Description	Quatity	Location
001	电阻,0 ohm,±5%,1/16W,0402	11	C419,LZ7,R4,R26,R601,R500,R504,R70,R71,R9(校准后删除),R3(校准后短
002	电阻,0 ohm,±5%,1/10W,0603	1	R406
003	电阻,0.36 ohm,±1%,1/4W,0805	1	R300
004	电阻,10 ohm,±5%,1/16W,0402	1	R35
005	电阻,33 ohm,±5%,1/16W,0402	7	R11,R13,R17,R64-R65,R7,R202
006	电阻,100 ohm,±5%,1/16W,0402	2	R205,R208
007	电阻,510 ohm,±5%,1/16W,0402	2	R200,R209
800	电阻,1K ohm,±5%,1/16W,0402	11	R2,R8,R204,R440-R441,R1,R15,R231,R405,R407-R408
009	电阻,1.5K ohm,±5%,1/16W,0402	3	R203,R207,R19
010	电阻,2K ohm,±5%,1/16W,0402	1	R206
011	电阻,4.7K ohm,±5%,1/16W,0402	2	R40,R41
012	电阻,6.8K ohm,±5%,1/16W,0402	3	R201,R24,R502
013	电阻,10K ohm,±5%,1/16W,0402	1	R16
014	电阻,15K ohm,±5%,1/16W,0402	1	R603
015	电阻,33K ohm,±5%,1/16W,0402	2	R14,R213
016	电阻,47K ohm,±5%,1/16W,0402	2	R5,R20
017	电阻,75K ohm,±5%,1/16W,0402	2	R18,R215
018	电阻,100K ohm,±5%,1/16W,0402	2	R214,R6
019	电阻,150K ohm,±5%,1/16W,0402	1	R36
020	电容,18pF,±5%,50V,COG,0402	5	C411,C414-C417
021	电容,2.2pF,±0.25pF,50V,COG,0402	4	C404-C405,C432,C433
022	电容,3.3pF,±0.25pF,50V,COG,0402	5	C639,C642-C644,C8
023	电容,4.7pF,±0.5pF,50V,COG,0402	1	C418
024	电容,6pF,±0.5pF,50V,COG,0402	3	C606,C611,C410
025	电容,10pF,±5%,50V,COG,0402	1	C401
026	电容,12pF,±5%,50V,COG,0402	4	ED3-ED6
027	电容,22pF,±5%,50V,COG,0402	4	C40,C601,C7,C203
028	电容,27pF,±5%,50V,COG,0402	1	C23
029	电容,33pF,±5%,50V,COG,0402	20	C3-C4,C14,C19-C21,C26,C28-C29,C31-C33,C47-C50,C208,VR2,C10,C
030	电容,39pF,±5%,50V,COG,0402	2	ED201,ED203
031	电容,47pF,±5%,50V,COG,0402	1 1	C614
032	电容,100pF,±5%,50V,COG,0402	9	C250,C13,C15,C219,C607,C406-C407,C409,C1243
033	电容,470pF,±10%,50V,X7R,0402	1 1	C44
034	电容,680pF,±10%,50V,COG,0402	2	C402-C403
035	电容,1nF,±10%,50V,X7R,0402	4	ED2,ED415,ED416,C449
036	电容,10nF,±10%,16V,X7R,0402	2	C38,C300
037	电容,22nF,±10%,16V,X7R,0402	4	C25,C204,C212,C221
037	电容,100nF,±10%,10V,X7K,0402	12	C200,C206,C217,C61,C600,C800-C801,C400,C501,C30,C802,C803

039	电容,1uF,±10%,10V,X5R,0603	4	C5,C58-C59,C56
040	电容,1uF,±10%,6.3V,X5R,0402	13	C1,C24,C41,C608,C613,C2,C17,C46,C51,C420-C423
041	电容,2.2uF,±10%,6.3V,X5R,0603	8	C218,C9,C60,C304-C305,C308-C310
042	电容,4.7uF,±10%,6.3V,X5R,0603	2	C57,C202
043	电容,10uF,±20%,6.3V,X5R,0805	7	C11,C609,C201,C213,C211,C303,C624
044	电感,2.4nH,±0.3nH,0402,SDCL1005C2N4STDF,SUNLORD	1	C618
045	电感,2.4nH,±0.3nH,0402,MGCl1005T2N4ST-LF,麦捷	1	C618
046	电感,6.2nH,±0.3nH,0402,SDCL1005C6N2STDF,SUNLORD	3	C619,L406,L407
047	电感,6.2nH,±5%,0402,MGCI1005T6N2JT-LF,麦捷	3	C619,L406,L407
048	电感,4.7nH,±0.3nH,0402,SDCL1005C4N7STDF,Sunlord	1	C463
049	电感,4.7nH,±0.3nH,0402,MGCI1005T4N7ST-LF,麦捷	1	C463
050	电感,10nH,±5%,0402,SDCL1005C10NJTDF,Sunlord	1	L400
051	电感,10nH,±5%,0402,MGCl1005T10NJT-LF,麦捷	1	L400
052	电感,15nH,±5%,0402,SDCL1005C15NJTDF,Sunlord	1	L403
053	电感,15nH,±5%,0402,MGCl1005T15NJT-LF,麦捷	1	L403
054	电感,100nH,±5%,0402,SDCL1005CR10JTDF,SUNLORD	1	L1
055	电感,100nH,±5%,0402,MGCl1005TR10JT-LF,麦捷	1	L1
056	(S)磁珠,75 ohm,600mA,0402,SZ1005G750TF,SUNLORD	2	LZ1-LZ2
057	(S)磁珠,75 ohm,300mA,0402,BLM15BB750SN1D,MURATA	2	LZ1-LZ2
058	(S)磁珠,75 ohm,300mA,0402,MGSB1005A750T-LF,麦捷	2	LZ1-LZ2
059	(S)磁珠,1000 ohm,250mA,0402,BLM15HD102SN1,MURATA	1	C45
060	(S)磁珠,1000 ohm,250mA,0402,HZ1005K102TFB01,SUNLORD	4	LZ201,LZ202,LZ207-LZ208
061	(N)磁珠,1.8K ohm,50mA,0402,HZ1005K182TF,SUNLORD	4	LZ3-LZ5,L800
062	(N)磁珠,1.8K ohm,50mA,0402,BLM15HD182SN1,Murata	4	LZ3-LZ5,L800
063	(S),磁珠,1.8K ohm,50mA,0402,MGGB1005M182HT-LF,麦捷	4	LZ3-LZ5,L800
064	(S)压敏电阻,5.5V,0402,SDV1005E5R5C400NPTF,Sunlord	3	ED10,ED220-ED221
065	(S)压敏电阻,5.5V,0402,AVLC5S02050,AMOTECH	3	ED10,ED220-ED221
066	(S)压敏电阻,5.5V,0402,ICVS0505500FR,ICT	3	ED10,ED220-ED221
067	(T)IC,MOSFET WITH SCHOTTKY,DFN3x2-8L,TPCF8B01,TOSHIBA	1	Q301
068	(S)IC,MOSFET(P-Channel),WDFN-8L3x2,RP1800CGQW,RICHPOWER	1	Q301
069	(S)IC,MOSFET WITH SCHOTTKY,WPM2005B-8/TR,DFN3x2-8L,WILL	1	Q301
070	(S)IC,MOSFET WITH SCHOTTKY,DFN3x2-8L,BF9024SPD-M,BYD	1	Q301
071	(S)IC,MOSFET WITH SCHOTTKY,DFN3x2-8L,SSF4703DC,SILIKRON	1	Q301
072	(S)二极管,肖特基,200mA,SOD-523,SIG631E30T1G,SIG	1	D413
073	(S)二极管,肖特基,200mA,SOD523,RB521S-30TE61,ROHM	1	D413
074	(S)二极管,肖特基,200mA,SOD523,DSF521,TOSHIBA	1	D413
075	(S)LED(蓝),0603,BL-HB336G-TRB,BRIGHT	4	LD1,LD4-LD5,LD34
076	(S)LED(蓝),0603,LTST-C193TBKT-5A,LITE-ON	4	LD1,LD4-LD5,LD34
077	(S)LED(蓝),0603,HT-193NB5,HARVATEK	4	LD1,LD4-LD5,LD34
078	(T)三极管,DTC114TKA,SC-59,ROHM	1	Q5
079	(T)三极管,RN1411,SC-59,Toshiba	1 1	Q5

081	080	(S)二极管,TVS,5V,80pf,SOD523,ESD5Z5.0T1G,ONSEMI	1	TVS301
10 10 10 10 10 10 10 10	081	i, i	1	TVS301
1	082	(S)二极管,TVS,7V,65pf,SOD-523,SIG5E7.OT1G,SIG	1	TVS301
1	083	(T)IC,基带芯片,SC6600L3(SC6600H3),展讯	1	U100
086	084	(S)IC,基带芯片,SC6600L2,展讯	1	U100
1	085	(T)IC,射频功放,GSM双频,AM7803P,AMALFI	1	U601
1	086	(N)FM芯片,4x4mm,RDA5802E,RDA	1	U1402
(S)読液器 SAWEGSMIDCS RX,EFCH9418TD1_PANASONIC	087	(T)IC,FM收发芯片,BK1080QB,QFN24,BEKEN	1	U1402
1990	088	(S)IC,射频收发器,GSM四频,QFN-40,QS518,展讯	1	U404
1	089	(S)滤波器,SAW,EGSM/DCS RX,EFCH9418TDL1,PANASONIC	1	U405
1 日本の	090	(S)滤波器,SAW,EGSM/DCS RX,SAWEN942MCN0F00,MURATA	1	U405
1	091	(S)滤波器,SAW,EGSM/DCS RX,SFR942PY002,WISOL	1	U405
1	092	(S)IC,MCP(32Mb+16Mb),ADMUX,M36W0R5040U6ZS L0,NUMONYX	1	U406
1	093	(S)IC,音频功放,AB类,UTQFN-9L,SN4990AIF09E,SI-EN	1	U201
1	094	(S)电池连接器,普通,3.0PITCH,8.4x3.5x6.2mmH,PAN30-03626-1500,LCN	1	U9
1	095	(S)电池连接器,普通,带定位柱,3PIN,3.0PITCH,8.4x3.5x6.2mmH,WKBAV006-	1	U9
1	096	电池连接器,普通,3.0PITCH,8.4x3.5x6.2mmH,TDBT01-3K5000,纽泰	1	U9
1	097	(S)SIM卡连接器,普通型,16.4x16.3x1.80mmH,SIMMS-00615-TP31(CAF99-	1	SIM1
100 (S)T-FLASH卡座,頼蓋型,14.5x13.6x1.9mmH,CAH11-08193-SF01,LCN	098	SIM卡连接器,普通型,16.1x16.4x1.8mmH,WKSM010-1911,杰顺通	1	SIM1
101 (S)T-FLASH卡座・旅盖型,1.93mmH,WKTFH010-S01,JTCONN	099	(S)SIM卡连接器,普通型,1.80mmH,TDSM01-6K5000,纽泰	1	SIM1
102 T-FLASH卡座,極盖型,1.9mmH,TDTS01-8K5000,纽泰	100	(S)T-FLASH卡座,掀盖型,14.5x13.6x1.9mmH,CAH11-08193-SF01,LCN	1	TF100
103 (S)Mini USB插座,12PIN,2.0mmH,MICFS-01215-TP03(UAF05-12204- 1 USB400 104 (T)MiNi USB插座,0.5PITCH,12PIN,2.0mmH,WKUBI008-001,杰順通 1 USB400 105 (T)MiNi USB插座,12PIN,2.0mmH,TDUB01-BK5000,组泰 1 USB400 106 (S)晶体,32.768KHz,±20ppm,12.5pF,Q13MC1462000200(Q13MC1461000200), 1 X200 107 (S)晶体,32.768KHz,±20ppm,12.5pF,SSP-T7-F,SII 1 X200 108 (S)晶体,32.768KHz,±20ppm,12.5pF,MS3V-T1R,MICRO 1 X200 109 (S)晶体,26MHz,±10ppm,8.0pf,3225,X1E000021002200/TN4-26245,EPSON 1 X400 109 (S)晶体,26MHz,±10ppm,9pF,3225,X3S0260000E9TH-NZ,HARMONY 1 X400 111 (S)晶体,26MHz,±10ppm,9pF,3225,X3S026000B9TH-NZ,HARMONY 1 X400 112 (S)晶体,26MHz,±10ppm,9pF,3225,7M26000056,TXC 1 X400 113 PCB±板,7707-MB-V1.3			1	111 1111
104 (T)MINI USB插座.0.5PITCH,12PIN,2.0mmH,WKUBI008-001,杰順通 1 USB400 105 (T)MINI USB插座,12PIN,2.0mmH,TDUB01-BK5000,组泰 1 USB400 106 (S)晶体,32.768KHz,±20ppm,12.5pF,C)13MC1462000200(Q13MC1461000200), 1 X200 107 (S)晶体,32.768KHz,±20ppm,12.5pF,SSP-T7-F,SII 1 X200 108 (S)晶体,32.768KHz,±20ppm,12.5pF,MS3V-T1R,MICRO 1 X200 109 (S)晶体,26MHz,±10ppm,8.0pf,3225,X1E000021002200/TN4-26245,EPSON 1 X400 110 (S)晶体,26MHz,±10ppm,7.4pF,3225,CX3225SB26000C4FZF06,KYOCERA 1 X400 111 (S)晶体,26MHz,±10ppm,9pF,3225,X3S026000B91H-NZ,HARMONY 1 X400 112 (S)晶体,26MHz,±10ppm,9pF,3225,X3S026000B91H-NZ,HARMONY 1 X400 113 PCB主板,7707-MB-V1.3 1	102		1	
105 (T)MINI USB插座,12PIN,2.0mmH,TDUB01-BK5000,纽泰 1 USB400 106 (S)晶体,32.768KHz,±20ppm,12.5pF,Q13MC1462000200(Q13MC1461000200), 1 X200 107 (S)晶体,32.768KHz,±20ppm,12.5pF,SSP-T7-F,SII 1 X200 108 (S)晶体,32.768KHz,±20ppm,12.5pF,MS3V-T1R,MICRO 1 X200 109 (S)晶体,26MHz,±10ppm,8.0pf,3225,X1E000021002200/TN4-26245,EPSON 1 X400 110 (S)晶体,26MHz,±10ppm,7.4pF,3225,CX3225SB26000C4FZF06,KYOCERA 1 X400 111 (S)晶体,26MHz,±10ppm,9pF,3225,CX3225SB26000C4FZF06,KYOCERA 1 X400 111 (S)晶体,26MHz,±10ppm,9pF,3225,X3026000B91H-NZ,HARMONY 1 X400 112 (S)晶体,26MHz,±10ppm,9pF,3225,7M26000056,TXC 1 X400 113 PCB±板,7707-MB-V1.3 1 1 (S)屏蔽罩、长方形带缺口,洋白铜,24.32x12.95x1.8mmH,7707 1 1 L452 116 (T)单内浏览效应管(-20V,-1.4A),WPM1480-3/TR,WILL 1 Q1 117 (T)P-FET(-20V,-1.37A),SIS4101PT1G,SOT-323,SIG 1 Q1 118 电感,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37 119 电感,3.9nH,±0.3nH,0402,MGCl1005T3N9ST-LF,支捷 1 C37	103	(S)Mini USB插座,12PIN,2.0mmH,MICFS-01215-TP03(UAF05-12204-	1	USB400
106 (S)晶体,32.768KHz,±20ppm,12.5pF,Q13MC1462000200(Q13MC1461000200),		(T)MINI USB插座,0.5PITCH,12PIN,2.0mmH,WKUBI008-001,杰顺通	1	
107 (S)晶体,32.768KHz,±20ppn,12.5pF,SSP-T7-F,SII 1 X200 108 (S)晶体,32.768KHz,±20ppm,12.5pF,MS3V-T1R,MICRO 1 X200 109 (S)晶体,26MHz,±10ppm,8.0pf,3225,X1E000021002200/TN4-26245,EPSON 1 X400 110 (S)晶体,26MHz,±10ppm,7.4pF,3225,CX3225SB26000C4FZF06,KYOCERA 1 X400 111 (S)晶体,26MHz,±10ppm,9pF,3225,X3S026000B91H-NZ,HARMONY 1 X400 112 (S)晶体,26MHz,±10ppm,9pF,3225,TM26000056,TXC 1 X400 113 PCB±板,7707-MB-V1.3 1 114 (S)屏蔽罩,长方形带缺口,洋白铜,24.32x12.95x1.8mmH,7707 1 115 电容,0.5pF,±0.25pF,50V,COG,0402 1 L452 116 (T)单P沟道场效应管(-20V,-1.4A),WPM1480-3/TR,WILL 1 Q1 117 (T)P-FET(-20V,-1.37A),SIS4101PT1G,SOT-323,SIG 1 Q1 118 电感,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37	105	(T)MINI USB插座,12PIN,2.0mmH,TDUB01-BK5000,纽泰	1	USB400
108 (S)晶体,32.768KHz,±20ppm,12.5pF,MS3V-T1R,MICRO			1	
109 (S)晶体,26MHz,±10ppm,8.0pf,3225,X1E000021002200/TN4-26245,EPSON 1 X400 (S)晶体,26MHz,±10ppm,7.4pF,3225,CX3225SB26000C4FZF06,KYOCERA 1 X400 (S)晶体,26MHz,±10ppm,9pF,3225,X3S026000B91H-NZ,HARMONY 1 X400 (S)晶体,26MHz,±10ppm,9pF,3225,7M26000056,TXC 1 X400 (S)晶体,26MHz,±10ppm,9pF,3225,7M26000056,TXC 1 X400 (S)晶体,26MHz,±10ppm,9pF,3225,7M26000056,TXC 1 X400 (S)屏蔽罩,长方形带缺口,洋白铜,24.32x12.95x1.8mmH,7707 1 (S)屏蔽罩,长方形带缺口,洋白铜,24.32x12.95x1.8mmH,7707 1 L452 (T)单P沟道场效应管(-20V,-1.4A),WPM1480-3/TR,WILL 1 Q1 (T)P-FET(-20V,-1.37A),SIS4101PT1G,SOT-323,SIG 1 Q1 日惠,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37 电惠,3.9nH,±0.3nH,0402,MGCl1005T3N9ST-LF,麦捷 1 C37	107	(S)晶体,32.768KHz,±20ppm,12.5pF,SSP-T7-F,SII	1	
110 (S)晶体,26MHz,±10ppm,7.4pF,3225,CX3225SB26000C4FZF06,KYOCERA	108	, ,	1	X200
111			1	
112 (S)晶体,26MHz,±10ppm,9pF,3225,7M26000056,TXC			1	
113 PCB主板,7707-MB-V1.3 1 114 (S)屏蔽罩,长方形带缺口,洋白铜,24.32x12.95x1.8mmH,7707 1 115 电容,0.5pF,±0.25pF,50V,COG,0402 1 L452 116 (T)单P沟道场效应管(-20V,-1.4A),WPM1480-3/TR,WILL 1 Q1 117 (T)P-FET(-20V,-1.37A),SIS4101PT1G,SOT-323,SIG 1 Q1 118 电感,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37 119 电感,3.9nH,±0.3nH,0402,MGCl1005T3N9ST-LF,麦捷 1 C37			1	
114 (S)屏蔽單,长方形带缺口,洋白铜,24.32x12.95x1.8mmH,7707 1 115 电容,0.5pF,±0.25pF,50V,COG,0402 1 L452 116 (T)单P沟道场效应管(-20V,-1.4A),WPM1480-3/TR,WILL 1 Q1 117 (T)P-FET(-20V,-1.37A),SIS4101PT1G,SOT-323,SIG 1 Q1 118 电感,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37 119 电感,3.9nH,±0.3nH,0402,MGCl1005T3N9ST-LF,麦捷 1 C37			•	X400
115 电容,0.5pF,±0.25pF,50V,COG,0402 1 L452 116 (T)单P沟道场效应管(-20V,-1.4A),WPM1480-3/TR,WILL 1 Q1 117 (T)P-FET(-20V,-1.37A),SIS4101PT1G,SOT-323,SIG 1 Q1 118 电感,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37 119 电感,3.9nH,±0.3nH,0402,MGCl1005T3N9ST-LF,麦捷 1 C37				
116 (T)单P沟道场效应管(-20V,-1.4A),WPM1480-3/TR,WILL 1 Q1 117 (T)P-FET(-20V,-1.37A),SIS4101PT1G,SOT-323,SIG 1 Q1 118 电感,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37 119 电感,3.9nH,±0.3nH,0402,MGCl1005T3N9ST-LF,麦捷 1 C37			<u> </u>	
117 (T)P-FET(-20V,-1.37A),SIS4101PT1G,SOT-323,SIG 1 Q1 118 电感,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37 119 电感,3.9nH,±0.3nH,0402,MGCl1005T3N9ST-LF,麦捷 1 C37				
118 电感,3.9nH,±0.3nH,0402,SDCL1005C3N9STDF,Sunlord 1 C37 119 电感,3.9nH,±0.3nH,0402,MGCI1005T3N9ST-LF,麦捷 1 C37		, ,		
119 电感,3.9nH,±0.3nH,0402,MGCl1005T3N9ST-LF,麦捷 1 C37			1	
			1	
120 电感,18nH,±5%,0402,SDCL1005C18NJTDF,Sunlord 1 L402			-	
	120	电感,18nH,±5%,0402,SDCL1005C18NJTDF,Sunlord	1	L402

121	电感,18nH,±5%,0402,MGCl1005T18NJT-LF,麦捷	1	L402
122	(S)滤波器,SAW,850-RX,SF14-0881M5UB50/A1,KYOCERA	1	U401
123	(S)滤波器,SAW,PCS1900-RX,SF14-1960M5UB50/A1,KYOCERA	1	U400

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